



Vishay Siliconix

Low Voltage, Low On-Resistance, Dual DPDT/Quad SPDT Analog Switch

DESCRIPTION

The DG2788, DG2789 are monolithic CMOS analog switching products designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2788, DG2789 are ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2788, DG2789 are built on Vishay Siliconix's low voltage process. An epitaxial layer prevents latchup. Breakbefore-make is guaranteed.

The switch conducts equally well in both directions when on, and blocks up to the power supply level when off. The DG2788 is configured as a dual Double Pole Double Throw switches while the DG2789 is configured as a Quad Single Pole Double Throw. The DG2789 has one control pin for all four SPDT switches and also has an enable pin that can turn all switches off.

The DG2788 and DG2789 comes in a small miniQFN-16 lead package (2.6 x 1.8 x 0.75 mm).

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations and is 100 % RoHS compliant.

FEATURES

- Low voltage operation (1.65 V to 4.3 V)
- Low on-resistance R_{ON} : 0.4 Ω typ. at 2.7 V
- Fast switching: t_{ON} = 47 ns
 - t_{OFF} = 15 ns
 - miniQFN-16 package
- Latch-up current > 300 mA (JESD78)

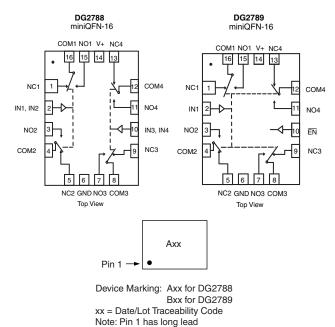
BENEFITS

- Reduced power consumption
- High accuracy
- Reduce board space
- TTL/1.8 V logic compatible
- High bandwidth

APPLICATIONS

- Cellular phones
- Speaker headset switching
- Audio and video signal routing
- PCMCIA cards
- Battery operated systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE (DG2788)					
Logic	ic NC1, 2, 3 and 4 NO1, 2, 3 and 4				
0	ON	OFF			
1	OFF	ON			

TRUTH TABLE (DG2789)						
EN Logic	IN Logic	NC1, 2, 3 and 4	NO1, 2, 3 and 4			
0	0	ON	OFF			
0	1	OFF	ON			
1	х	OFF	OFF			

ORDERING INFORMATION					
Temp. Range	Temp. Range Package Part Number				
- 40 °C to 85 °C	miniQFN-16	DG2788DN-T1-E4 DG2789DN-T1-E4			



COMPLIANT

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ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter		Symbol	Limit	Unit		
Deference to OND	V+		- 0.3 to 5.0	V		
Reference to GND	IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3)	v		
Current (Any terminal except NO, NC or COM)			30			
Continuous Current (NO, NC, or COM)			± 300	mA		
Peak Current (Pulsed at 1 ms, 10 % duty cycle)			± 500			
Storage Temperature (D Suffix)			- 65 to 150			
Package Solder Reflow Conditions ^d	miniQFN-16		250			
Power Dissipation (Packages) ^b miniQFN-16 ^c			525	mW		

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 6.6 mW/°C above 70 $^\circ\text{C}$

d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.



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SPECIFICATIONS ((V+ = 3 V)						
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	V+ = 3 V, \pm 10 %, V _{IN} = 0.5 or 1.4 V ^e	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit
Analog Switch	-					<u> </u>	
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V
		$V_{+} = 2.7 V, V_{COM} = 0.5 V, I_{NO}, I_{NC} = 100 mA$	Room		0.4	0.5	
On-Resistance	R _{ON}	V + = 2.7 V, V_{COM} = 1.5 V, I_{NO} , I_{NC} = 100 mA			0.33	0.5	
			Full			0.56	Ω
R _{ON} Flatness ^d	R _{ON} Flatness	$V_{+} = 2.7 V, V_{COM} = 0 \text{ to } V_{+},$	Room		0.1	0.15	22
R _{ON} Match ^d	ΔR_{ON}	I _{NO} , I _{NC} = 100 mA	Room		0.05		
	I _{NO(off)} ,		Room	- 1		1	
Switch Off Leakage Current	I _{NC(offF)}	V+ = 3.3 V, V _{NO} , V _{NC} = 0.3 V/3.0 V,	Full	- 10		10	
ownen on Leakage ourrent	I _{COM(off)}	V _{COM} = 3.0 V/0.3 V	Room	- 1		1	nA
			Full	- 10		10	
Channel-On Leakage Current	I _{COM(on)}	V+ = 3.3 V, V _{NO} , V _{NC} = V _{COM} = 0.3 V/3.0 V	Room Full	- 1 - 10		1 10	
Digital Control					I		
Input High Voltage	V _{INH}		Full	1.4			
Input Low Voltage	V _{INL}		Full			0.5	V
Input Capacitance	C _{in}		Full		6		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	- 1		1	μA
Dynamic Characteristics					1		
Turn-On Time	t _{ON}		Romm Full		47	72 75	
Turn-Off Time	t _{OFF}	V_{NO} or V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF	Room Full		15	43 45	ns
Break-Before-Make Time	t _d		Full	1			
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		87		рС
Off to start and	OIRR	$R_L = 50 $ Ω, $C_L = 5 $ pF, f = 100 kHz			- 69		
Off-Isolation ^d	UINN	$R_L = 50 $ Ω, $C_L = 5 $ pF, f = 1 MHz	Room		- 49		
d f	V	$R_L = 50 $ Ω, $C_L = 5 $ pF, f = 100 kHz			- 106		dB
Crosstalk ^{d, f}	X _{TALK}	$R_L = 50 $ Ω, $C_L = 5 $ pF, f = 1 MHz			- 96		
N. N. Off. Organistic and	C _{NO(off)}		Room		81		
N_{O} , N_{C} Off Capacitance ^d	C _{NC(off)}		Room		81		
	C _{NO(on)}	f = 1 MHz	Room		186		pF
Channel-On Capacitance ^d	C _{NC(on)}		Room		186		
Power Supply		·					
Power Supply Range	V+			2.7		3.3	V
Power Supply Current	l+	V _{IN} = 0 or V+	Full			1.0	μA

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SPECIFICATIONS $(V + = 4.3 V)$								
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C				
Parameter	Symbol	V+ = 4.3 V, V_{IN} = 0.5 or 1.6 V ^e	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit	
Analog Switch		-				•		
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V	
		$V + = 4.3 V, V_{COM} = 0.9 V, I_{NO}, I_{NC} = 100 mA$	Room		0.32	0.45		
On-Resistance	R _{ON}	$V + = 4.3 V$, $V_{COM} = 2.5 V$, I_{NO} , $I_{NC} = 100 mA$			0.27	0.45		
			Full			0.5	0	
R _{ON} Flatness ^d	R _{ON} Flatness	$V_{+} = 4.3 V, V_{COM} = 0 \text{ to } V_{+},$	Room		0.1	0.15	Ω	
R _{ON} Match ^d	ΔR_{ON}	I _{NO} , I _{NC} = 100 mA	Room		0.03			
Switch Off Leakage Current ^d	I _{NO(off)} , I _{NC(offF)}	V+ = 4.3 V, V _{NO} , V _{NC} = 0.3 V/4.0 V,		-10 - 100		10 100		
	I _{COM(off)}	V _{COM} = 4.0 V/0.3 V	Room Full	- 10 - 100		10 100	nA	
Channel-On Leakage Current ^d	I _{COM(on)}	$V_{+} = 4.3 V, V_{NO}, V_{NC} = V_{COM} = 3.0 V/4.0 V$	Room Full	- 10 - 100		10 100		
Digital Control								
Input High Voltage	V _{INH}		Full	1.6			V	
Input Low Voltage	V _{INL}		Full			0.5	v	
Input Capacitance	C _{in}		Full		6		pF	
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	- 1		1	μA	
Dynamic Characteristics			-					
Charge Injection ^d	Q _{INJ}	${\sf C}_{\sf L}$ = 1 nF, ${\sf V}_{\sf GEN}$ = 0 V, ${\sf R}_{\sf GEN}$ = 0 Ω	Room		105		рС	
N _O , N _C Off Capacitance ^d	C _{NO(off)}		Room		79		рF	
N _O , N _C OII Capacitance	C _{NC(off)}	f = 1 MHz	Room		79			
Channel-On Capacitance ^d	C _{NO(on)}		Room		183		рг	
	C _{NC(on)}		Room		183			
Power Supply								
Power Supply Range	V+					4.3	V	
Power Supply Current	l+	V _{IN} = 0 or V+	Full			1.0	μA	

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, not subjected to production test.

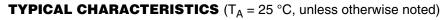
e. V_{IN} = input voltage to perform proper function.

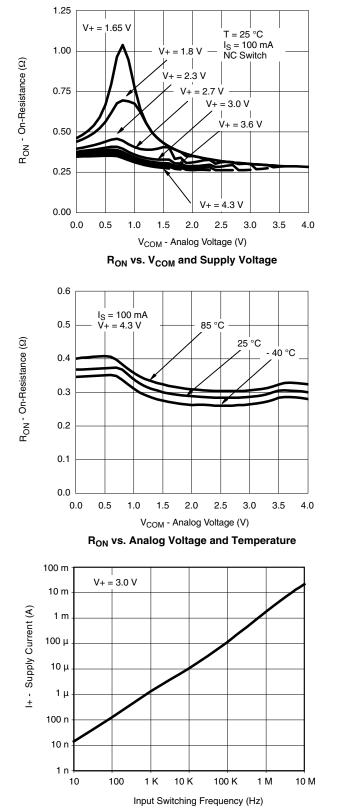
f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

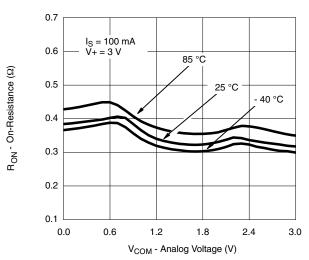


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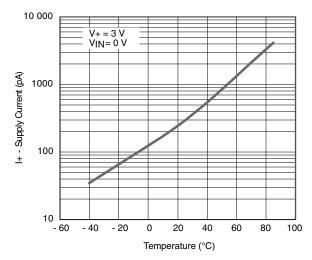




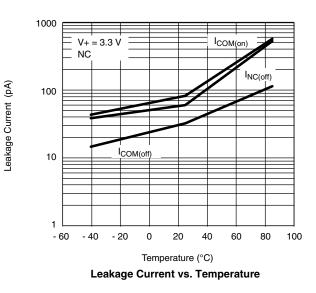




R_{ON} vs. Analog Voltage and Temperature

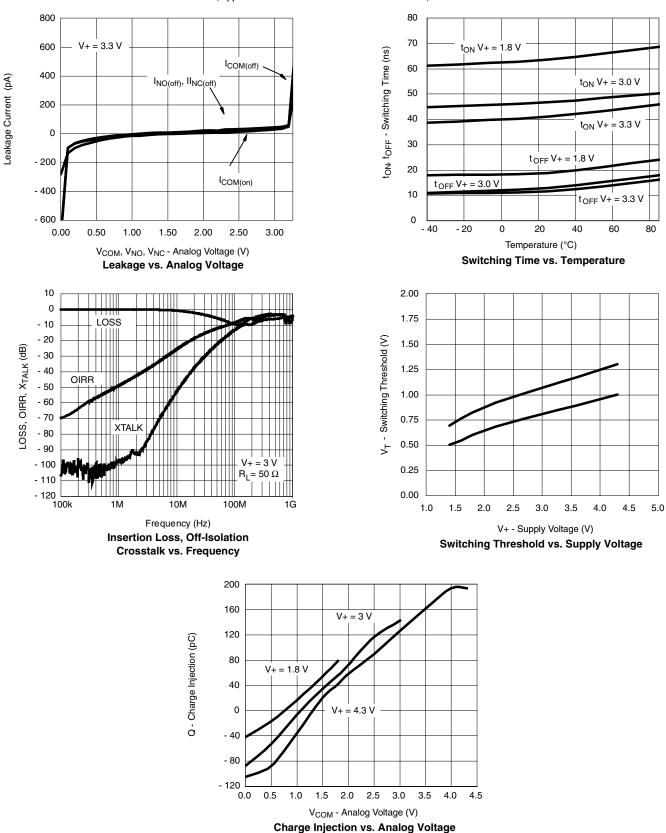


Supply Current vs. Temperature



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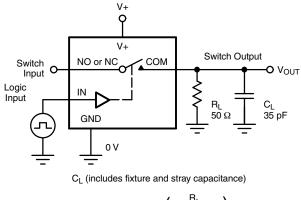


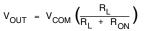
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

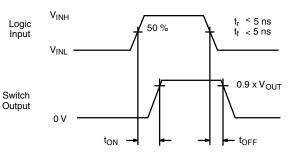


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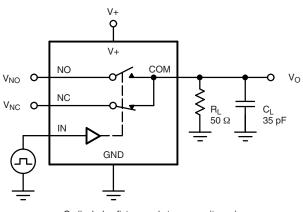


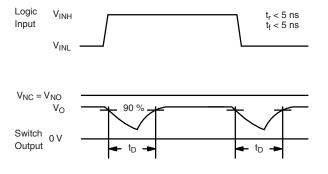




Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

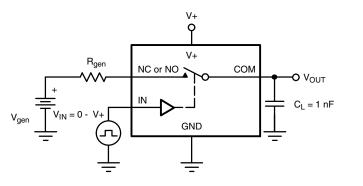


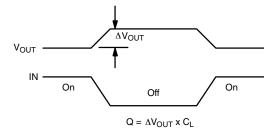




C_L (includes fixture and stray capacitance)

Figure 2. Break-Before-Make Interval



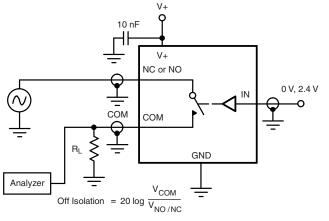


IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

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TEST CIRCUITS



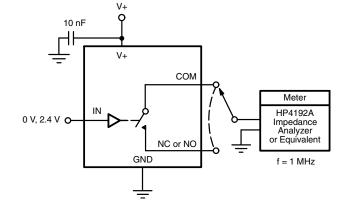


Figure 4. Off-Isolation

Figure 5. Channel Off/On Capacitance

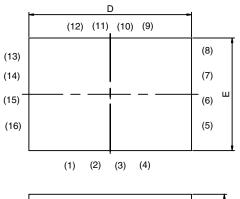
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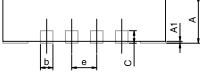


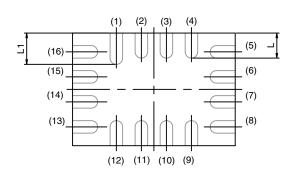


Package Information Vishay Siliconix

MINI QFN-16L







BACK SIDE VIEW

DIM	MILLIMETERS			INCHES			
DIV	MIN.	NAM	MAX.	MIN.	NAM	MAX.	
А	0.70	0.75	0.80	0.0275	0.0295	0.0315	
A1	0	-	0.05	0	-	0.002	
b	0.15	0.20	0.25	0.0059	0.0078	0.0098	
С	0.15	0.20	0.25	0.0059	0.0078	0.0098	
D		2.60 BSC		0.1023 BSC			
Е	1.80 BSC			0.0708 BSC			
е		0.40 BSC			0.0157 BSC	;	
L	0.35	0.40	0.45	0.0137	0.0157	0.0177	
L1	0.45	0.50	0.55	0.0177 0.0196 0.02		0.0216	

ECN T-06380-Rev. A, 14-Aug-06	
DWG: 5954	



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